On the necessity for systematic study of K emission in non-refluxing conditions

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Motivation

The Ka emission is a widely used diagnostic to track the fast electron beam transport in target material.

It can give information on fast electron penetration depth, spreading angle and laser to electron conversion efficiency.

As proved experimentally, K emission depends on plasma parameters, more specifically on the plasma gradients at the target interface, that determine the fast electron refluxing. There's a need for a more detailed study of K emission in non relfuxing condition to better understand the details of fast electron transport in target material.

The experimental setup was composed by many diagnostic, for our purpose we will show only the K-alpha imaging diagnostics



Shot for 3.9Au/15CH/5Cu/20Al in refluxing conditions

K back



Side on K



Shot for 3.9Au/15CH/5Cu/20Al with get lost layer



Only SP

With LP

Shot for 0.1AI/25CH/5Cu/12.5Au

With LP

Only SP







Other works



A long pulse focused on the target rear produces a 60 µm scale lenght plasma, 10¹⁹ cm⁻³ electron density.

Yabuuchi et al, Phys. Plasmas 14, 040706 2007

Other works



Yabuuchi et al, Phys. Plasmas 14, 040706 2007

"Transverse" targets

It is possible to see the "exponential" decay of Ka radiation followed by a rise up due to fast electron refluxing at the rear surface



Cone-wire targets

Cone-wire targets from "fast electron transport" experiment at TAP

The wires are 400 μm long



The total number of Ka photons produced in a single passage in the tracer layer is given by

$$N_{K} = \int_{E_{K}}^{\infty} \sigma(E) f(E, \mathbf{X}) \omega_{K} n_{Cu} \lambda \left(1 - e^{-\frac{L_{Cu}}{\lambda}} \right) dE$$

where $\sigma(E)$ is the relativistic cross section for K-shell ionization

$$\sigma_{K,\text{Re}}(E)(cm^{2}) = 7.92 \times 10^{-14} \frac{1}{EE_{K}} R(E) \ln \frac{E}{E_{K}}$$

and R(E) is the relativistic correction factor

$$\boldsymbol{R}(\boldsymbol{E}) = \left(\frac{2+\boldsymbol{E}_{K}}{2+\boldsymbol{E}}\right) \left(\frac{1+\boldsymbol{E}}{1+\boldsymbol{E}_{K}}\right)^{2} \left(\frac{(\boldsymbol{E}_{K}+\boldsymbol{E})(2+\boldsymbol{E})(1+\boldsymbol{E}_{K})^{2}}{\boldsymbol{E}(2+\boldsymbol{E})(1+\boldsymbol{E}_{K})^{2}+\boldsymbol{E}_{K}(2+\boldsymbol{E}_{K})}\right)^{\frac{3}{2}}$$

The fast electron distribution function has been chosen so that

$$f(E, \mathbf{x}) = f(E) N_{e0} e^{-\frac{\mathbf{x}}{\lambda}}$$

where f(E) is a relativistic Maxwellian, assumed to do not vary in shape but only in number of particles during the transport

 x_T is the tracer layer depth in the target, for simplicity, the target is assumed symmetrical with respect to the tracer layer, but the model is applicable to different target designs .



We define the integral as:

$$\int_{E_K}^{\infty} N_{e0} \sigma(E) f(E) \omega_K n_{Cu} \lambda \left(1 - e^{-\frac{L_{Cu}}{\lambda}} \right) e^{-\frac{K_T}{\lambda}} dE = f_{e \to K}$$

The refluxing electron beam will produce:

$$\begin{split} R \cdot e^{-\frac{(2x_T + L_{Cu})}{\lambda}} f_{e \to K} + R^2 \cdot e^{-\frac{(4x_T + 2L_{Cu})}{\lambda}} f_{e \to K} + \dots \to \\ \to \sum_{j} \left(R \cdot e^{-\frac{(2x_T + L_{Cu})}{\lambda}} \right)^j f_{e \to K} = \frac{1}{1 - R \cdot e^{-\frac{(2x_T + L_{Cu})}{\lambda}}} f_{e \to K} \end{split}$$

Where R is the reflection coefficient, 0 R 1

We can calculate the total K yield as function of the reflection coefficient R, for laser and target specs similar to the Titan laser conditions



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In the case of low contrast pulses -undriven target and high contrast driven target, we have two different reflection coefficients for front and rear side, R and r. We need to consider four cases:

Undriven- High contrast SP
Undriven- Low contrast SP
Driven- High contrast SP

$$N_{K} = \frac{1}{1 - R \cdot e^{-2 x_{T} - L_{Cu}/\lambda}} f_{e \to K}$$

$$N_{K} = \frac{(1 + R)}{1 - R r e^{-2 x_{T} - L_{Cu}/\lambda}} f_{e \to K}$$

$$N_{K} = \frac{(1 + r)}{1 - R r e^{-2 x_{T} - L_{Cu}/\lambda}} f_{e \to K}$$

$$N_{K} = \frac{1}{1 - r \cdot e^{-2 x_{T} - L_{Cu}/\lambda}} f_{e \to K}$$

The reflection coefficient is determined only by plasma conditions at the interface.



Collisional Simulation

We performed a collisional simulation to verify the effective increment in the k-alpha yield in refluxing conditions. Propagation in a 20/5/20 um Al/Cu/Al target

"Flat" fast electron distribution 1 MeV, 1.4 x 10¹¹ e⁻/cm² and refluxing coef. R=0.85





Collisional Simulation

Fast electron flux in the tracer layer.

In the simulation we consider 2 refluxes







Collisional Simulation

K photon flux after the tracer layer.

These images are correspondent to those for electron fluxes



Conclusion

We developed a 1-D analytical model to describe the Ka yield with refluxing.

A reflection coefficient R , that contains the physics at the target plasma interface, has been introduced.

The measure of the reflection coefficient is important for the physics of electron guiding devices like cones or wires: what are the plasma conditions that "keep" the guiding properties of such devices?

We measured R for "classic" fast electron transport experiment finding R=0.8 in absence of get lost layer: need for absolute k-alpha yield measurements in non refluxing conditions to estimate R, coupled with interferometer diagnostic to characterize the plasma and associate R to the plasma gradients.